

# Syrnatec Inc. Product Catalog

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# **IMAGING SOLUTIONS**

# MSI IMAGER INFRARED

# MSI: Multispectral Imagers (TRL Status: TRL-4)

The MSI is a Multispectral off-the-shelf Ultra low light color night vision imaging system. MSI features cutting edge wide spectrum focal plane array to support ultra-low light color imaging needs.

### **Specifications**

- Imager: WSFPA Photodetector, 400nm to 1800nm, 8μm pixels, 2Kx2K pixel density
- Resolution: 1080p, 1080i
- Image enhancement: Antiblooming, Auto pixel correction, Anti reflective coating on FPA/ Solar/ intense source protection
- Video connectivity: HD-SDILow light detectivity: 0.0001lx
- Gain: adjustable
- Color: Manual and auto adjust

# **FOCAL PLANE ARRAYS**

- SWIR FPA
- ➢ NIR FPA
- MWIR FPA
- LWIR FPA

# RADIATION HARDENED ROIC

ROIC is a 16 Readout Integrated IC with a 12-bit ADC working up to 20Mbps (3 to 20Msps). Standard Device offers 16 LVDS output. Device is suitable to read raw data from CCD/ CMOS sensor. ROICs are designed for both Scanning and Staring application

ROICs are available for:

- Visual and Near IR
- LWIR
- ➤ Hyper Spectral\*

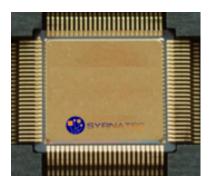
Customized devices with following functional features can also be offered

ADC: 14-bit ADC (up to 20Msps)
No. of Channels: 4 to 16 channel options

\*Hyperspectral imaging Sampling frequency: few KHz to 20MHz to support

Device is offered with:

Package: 120 PGA and 100 CQFP



### **Electrical Specification**

- Input voltage: 3.3V
- Digital Core voltage: 2.5V
- Analog I/O: 3.3V
- Power Consumption: < 70mW/ Channel@20Msps

# **Environmental Specification**

- Operating Temperature: -55 to +125degC
- TID: upto 300Krad (Si)
- SEL immune (LETTH): > 64MeV/mg/cm2
- SEU Immune (LETTH): > 40MeV/mg/cm2

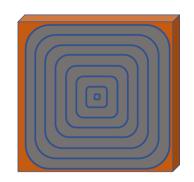
# **DETECTORS AND SENSORS**

# SILICON DRIFT DETECTOR

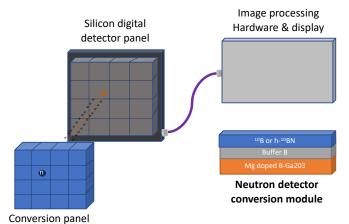
Syrnatec X-DD is a large area silicon drift detectors of 1cm3, under development for measurement of Medium energy X-Rays. Detectors consist of a fully depleted, high resistivity silicon active area. Incident X-rays will be determined by monitoring the magnitude of the voltage step after each pulse that is incident on X-DD.

The detector and read out electronics are currently under development. Product is expected to reach TRL-3 by Q4-2021.

Syrnatec intends to develop these detectors as single detector and integrated FPAs for applications covering NDT, medical imaging, High-energy physics, Electron Microscopy, Spectroscopy.



### NEUTRON DETECTOR



High performance thermal solid-state neutron detector panel is designed to operate from 1 MeV to 8 MeV with neutron density 10 neutron/cm2/sec.

A unique structure is built on a Ga2O3 substrate coated with H-10BN.

It has High Spatial Resolution of 0.5 mm or better Signal to Noise Ratio (SNR): >12, Gamma Sensitivity: > 10-6. Syrnatec intend to develop a neutron detector for covering applications such as Critical Aerospace NDT techniques in turbines and other vital assemblies, Inspection of Material Science, Munition Detection.

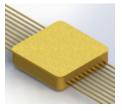
# INTEGRATED CIRCUITS

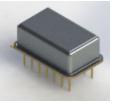
# CRYSTAL OSCILLATOR

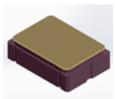
- ➤ Hi precision crystal oscillator
- Frequency range: 10KHz to 250MHz
- Available in Industrial, MIL and Class S Radiation hardened version

### Package option:

- SMT (5x7, 7x9, Flatpack)
- > Thru hole (5x7, 7x9, DIL)







### **Electrical Specification**

Input Voltage: 3.3V/ 5V

# **Environmental Specification**

- Operating Temperature: -55 to +125degC
- > TID: up to 100Krad (Si)





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